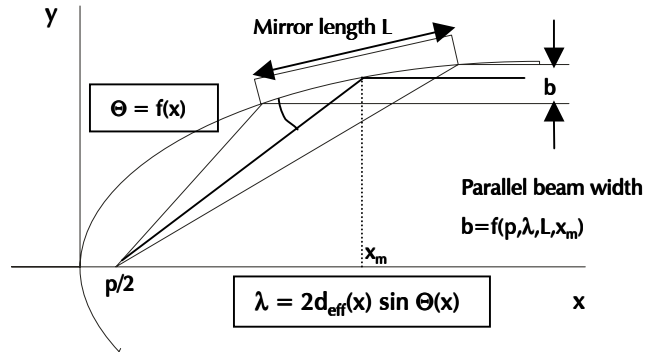


PARALLEL BEAM X-RAY OPTICS

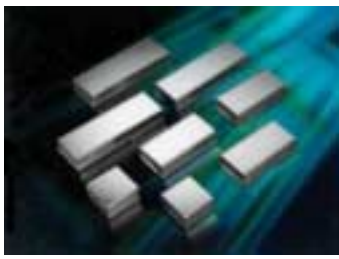


Fabrication of high precision 60 mm parallel beam optics both on prefigured substrates (right) and on flat substrates, which are glued and bend after deposition (left)



Generation of a monochromatic parallel beam in one dimension

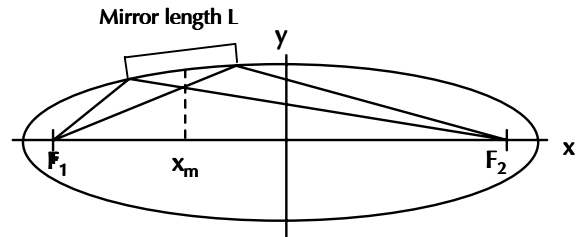
Spectral lines:	Cr, Co, Cu, Mo, Ag (others on request)
Mean Reflectivity:	$R > 70\%$
Monochromasy:	$K\alpha_1 + K\alpha_2$
Divergence:	$\Delta\phi \leq 0.03^\circ$
Mirror length:	20mm - 80mm (on customers request)
X- ray source geometry:	Line focus preferred
Parallel beam width b:	dependent on spectral line, geometry and mirror length $b=0.8\text{mm}$ (Cu, 40mm, $x_m = 90\text{ mm}$)
Geometry:	distance source-mirror (middle pos.- x_m) standard mirror (40mm) $x_m = 90\text{mm}$ standard mirror (60mm) $x_m = 100\text{mm}$



FOCUSSING X-RAY OPTICS



Parallel beam and focussing X-ray optics with various geometries



Generation of a monochromatic focussing beam in one dimension

Spectral lines:

Cr, Co, Cu, Mo, Ag (others on request)

Mean reflectivity:

$R > 70\%$

Monochromasy:

$K\alpha_1 + K\alpha_2$

Mirror length:

20mm - 80mm (on customers request)

X-ray source geometry:

Line focus preferred

Width of focus b:

dependent on spectral line, geometry and mirror length

Geometry:

customized

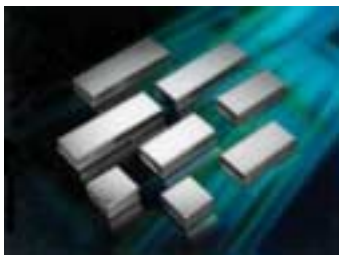
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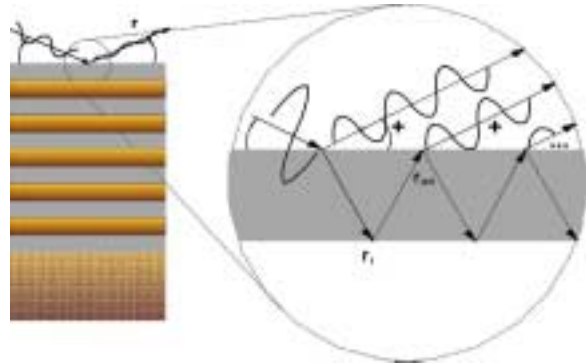
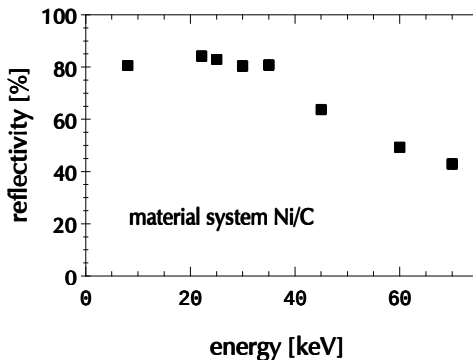
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MONOCHROMATORS



Spectral range :

100 eV – 100 keV

Material systems:

optimized on wavelength, on customers request

Dimensions:

up to 6" diameter, others on request

Thickness homogeneity:

$\Delta d/d < 1\%$

Applications:

monochromators on laboratory X-ray sources and on synchrotrons

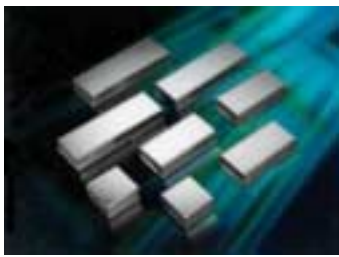
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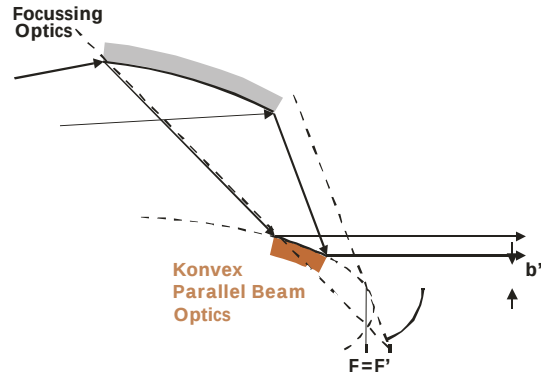
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KONVEX PARALLEL BEAM OPTICS



Generation of a compressed monochromatic parallel beam (width b) in one dimension

Outstanding Feature:

Spectral lines:

Mean reflectivity:

Monochromasy:

Mirror length:

X-ray source geometry:

Geometry:

Increase of the parallel beam photon flux in combination with a focusing optic by reduction of beam width b compared to conventional parallel beam optics

Cr, Co, Cu, Mo, Ag (others on request)

$R > 70\%$

$K\alpha_1 + K\alpha_2$

20mm - 40mm (on customers request)

Line focus preferred

customized

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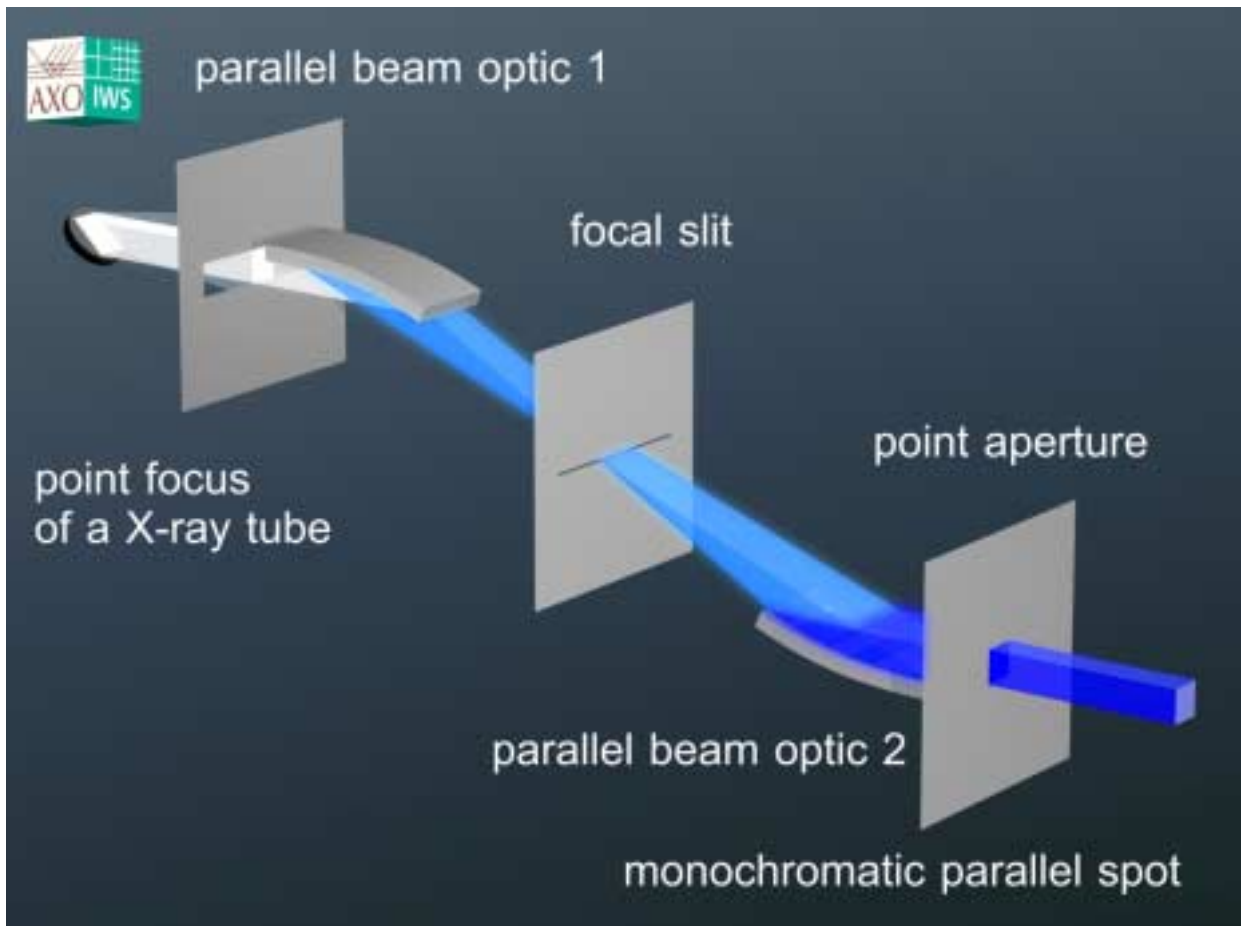
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COLLIMATING MONOCHROMATOR



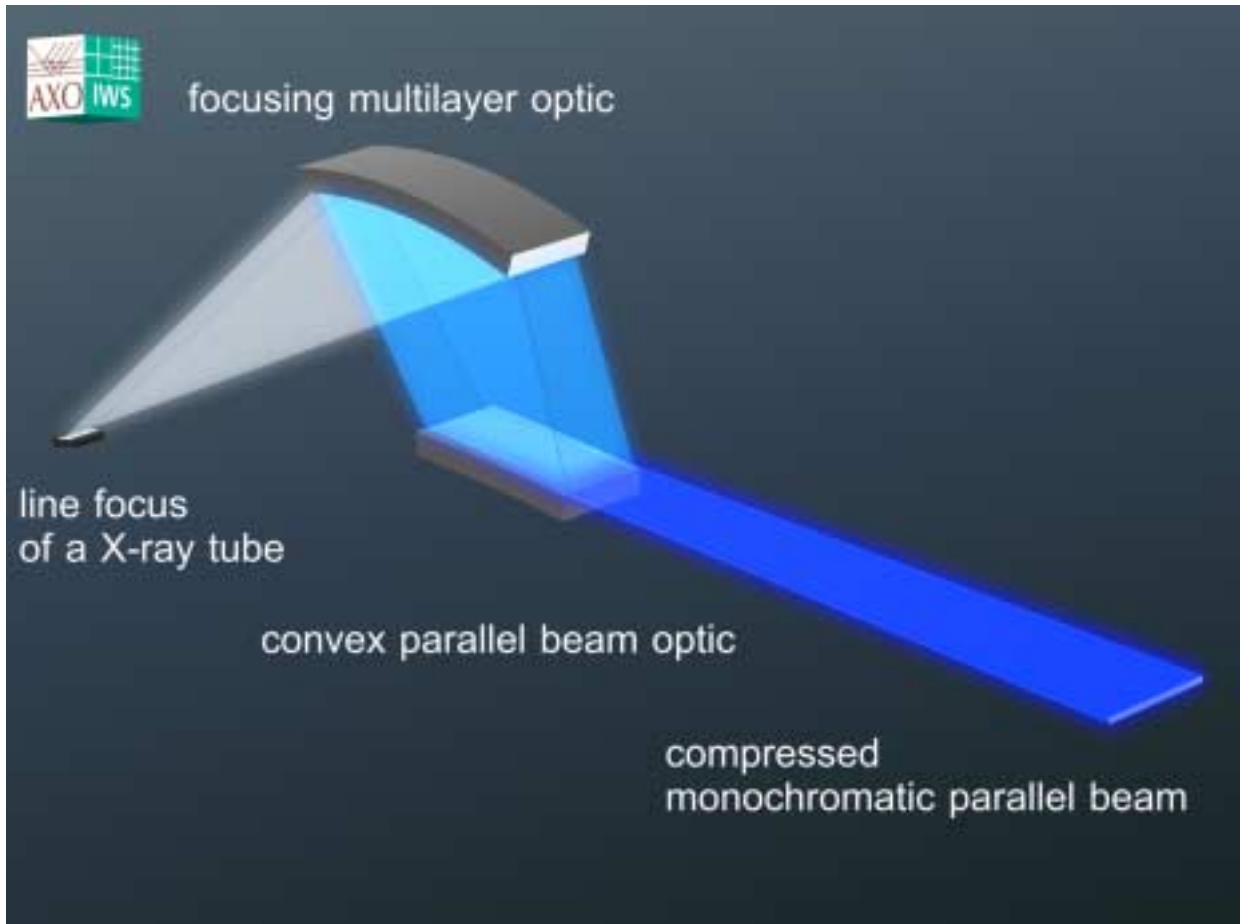
Two parallel beam optics, aligned on the same focal point

Acceptance of parallel X-radiation emitted by a point focus X-ray source (e.g. 0.3mm x 0.3mm rotating Mo anode)

Result:
monochromatic ($K\alpha_{1,2}$) parallel spot



BEAM COMPRESSOR



Combination of focussing and collimating multilayer optics

Emission of a parallel monochromatic beam

Adjustable beam width b at sample position

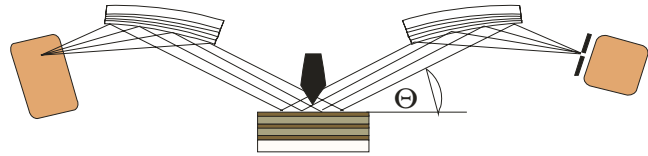
Result:

monochromatic ($K\alpha_{1,2}$) parallel spot with a width $b < 0.3$ mm

Application: microdiffractometry and -tomography



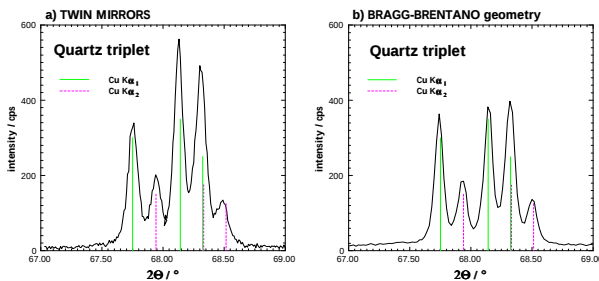
TWIN MIRROR KIT



Setup of TWIN MIRROR arrangement

Twin Mirror Kit – left: primary mirror housing,
right: secondary mirror housing with beam tube and slit holder

A new quality in X-ray diffractometry – secondary parallel beam optics



Better resolution than soller slits because
of a more than two times lower angular
acceptance (Cu K α : $\Delta\phi < 0.03^\circ$)

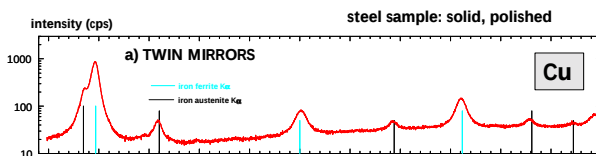
Transmission higher than 70%

Increased S/N-ratio due to sample
fluorescence suppression

Fits best to primary parallel beam optics

Parallel beam geometry:

- simplified sample preparation
- increased accuracy



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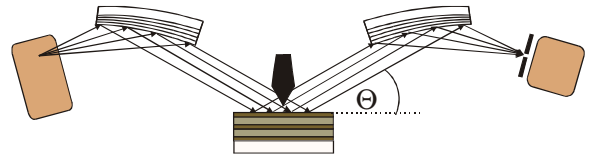
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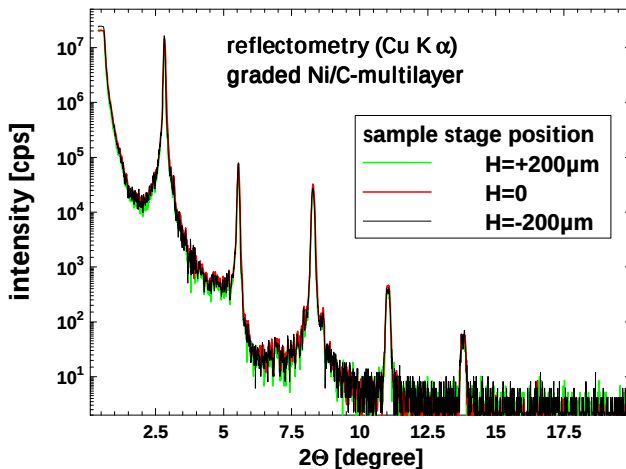
TWIN MIRROR KIT



Setup of TWIN MIRROR arrangement

Twin Mirror Kit – left: primary mirror housing,
right: secondary mirror housing with beam tube and slit holder

A new quality in in-house X-ray reflectometry – TWIN MIRROR Arrangement



No influence of sample displacement errors up to 200 μm on peak position and intensity

Sample alignment within **10 seconds**

Dynamic range of more than **7 orders** of magnitude

Low divergence (Cu $K\alpha$: $\Delta\phi < 0.02^\circ$)

Detectable thin film thicknesses between **2nm and 270nm**

Upgrade available for Cr $K\alpha$, Co $K\alpha$, Cu $K\alpha$, Mo $K\alpha$, Ag $K\alpha$
Geometry on customer request

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Application of Nanometer-Multilayer Optics for X-ray Analysis

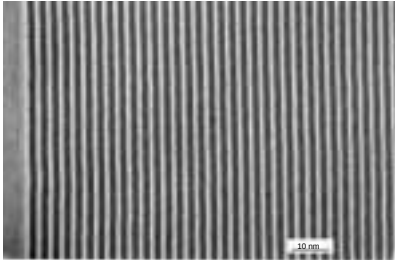
R. Dietsch^{*/**}, St. Braun^{*}, Th. Holz^{**}, A. Leson^{*}

^{*}Fraunhofer Institute Material and Beam Technology (IWS), Winterbergstr. 28, D-01277 Dresden, Germany: www.iws.fhg.de

^{**}AXO DRESDEN GmbH, Siegfried-Rädel-Str.31, D-01809 Heidenau, Germany:

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High performance focusing and parallel beam multilayer X-ray optics

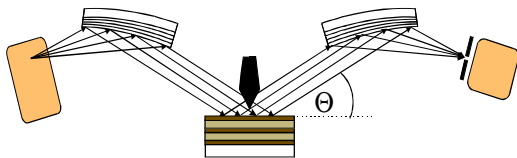


Ni/C multilayer
($d=3.2$ nm)
(TEM cross section)

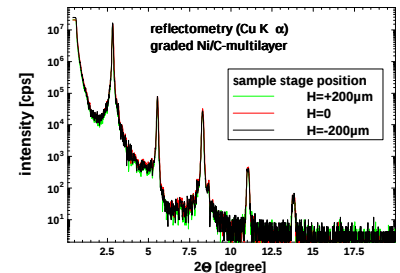


Glued and prefigured focusing and parallel beam X-ray optics with various focal lengths and parallel beam widths, designed for Mo $K\alpha$ -, Cu $K\alpha$ -, Co $K\alpha$ -radiation

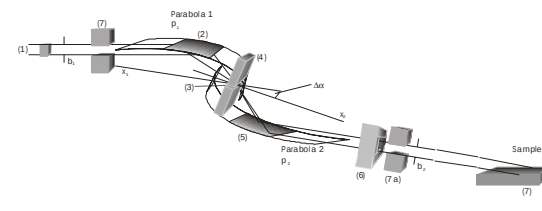
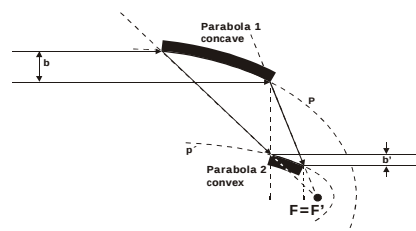
A new quality of in-house X-ray reflectometry - Twin mirror arrangement



- highest intensity and low divergence
- superior $K\beta$ - suppression
- sample fluorescence suppression
- no influence of sample surface position errors on peak position for reflectometry and diffractometry
- easy and fast sample alignment



High brilliance collimating monochromator systems for intense sub-mm X-ray spots X-ray Pointer and Beam Compressor



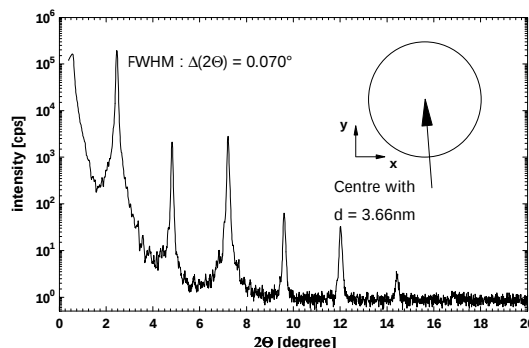
Beam Compressor

sub-mm Reflectometry

Thickness Gradient
perpendicular
to beam direction

(Ni/C graded multilayer)

(Beam Compressor spot
0.3mm x 0.6mm (Z x Y);
Twin mirror arrangement)



Collimating Monochromator

FUTURE POTENTIALS in

- Micro-Diffraction, Reflectometry
- X-Ray Micro-Lithography
- Micro-Tomography
- Single Crystal Diffractometry

X-ray Pointer and Beam Compressor – high brilliance collimating monochromator systems for intense sub-mm X-ray spots

Reiner Dietsch^{*/**}, Thomas Holz^{**}

^{*}Fraunhofer Institute Material and Beam Technology (IWS), Winterbergstr. 28, D-01277 Dresden, Germany

^{**}AXO DRESDEN GmbH, Siegfried-Rädel-Str.31, D-01809 Heidenau, Germany

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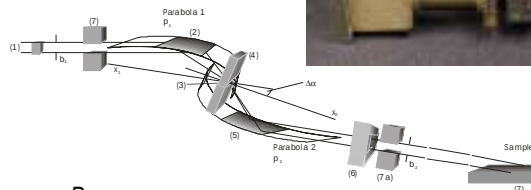
Modules and Design



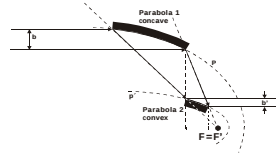
Glued and prefabricated X-ray mirrors with different lengths and convex and concave parabolic shape designed for Mo, Cu, Co $K\alpha$ -radiation

- Two parallel beam optics aligned on the same focal point
- Acceptance of parallel X-radiation emitted by a point focus X-ray source (e.g. 0.3mm x 0.3mm rotating anode)
- Result: a monochromatic ($K\alpha_{1,2}$) parallel spot

Collimating Monochromator

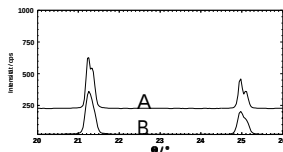


Beam Compressor



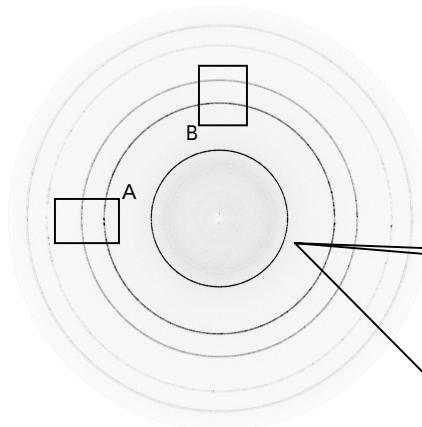
XRD-Application*

*Ch. Baerlocher, ETH Zurich



integrated intensities of rectangles A and B

comparable resolution by means of parallel beam optics (A) and slits (B)



Si powder sample

Illuminated area 0.3mm x 0.3mm

Mo rotating anode tube 50kV/90mA

Marresearch IP Detector

sample-detector distance 300mm

Si (111)

Separation $K\alpha_1$ and $K\alpha_2$ reflection

FWHM: only 1 or 3 pixel, resp.

sub-mm Reflectometry

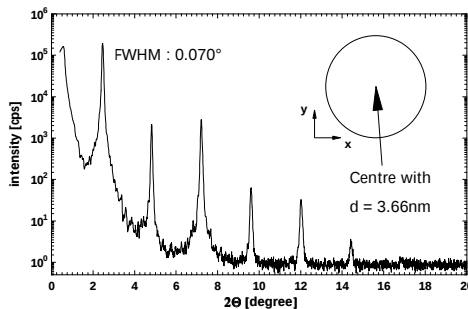
Ni/C graded multilayer on 4" Si-wafer (inset)

Thickness Gradient perpendicular to beam direction

40kV/40mA
Cu fixed anode tube
point fokus 1,2mm x 0.4mm

Beam Compressor spot
0.3mm x 0.6mm (Z x Y)

Geometry: Twin arrangement



FUTURE POTENTIALS in

- μ -DIFFRACTION, REFLECTOMETRY
- X-RAY μ -LITHOGRAPHY
- μ -TOMOGRAPHY
- SINGLE CRYSTAL DIFFRACTOMETRY

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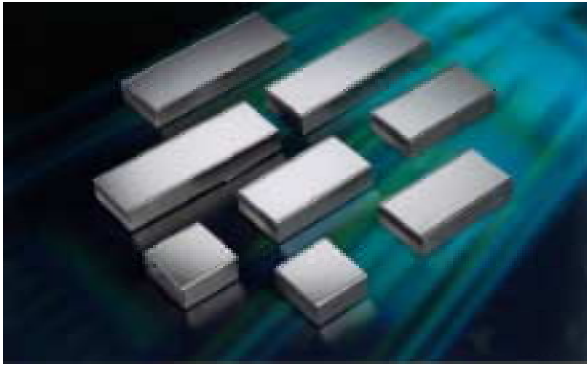


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Parallel beam X-ray optics for CrK α , CoK α , CuK α , MoK α , AgK α radiation

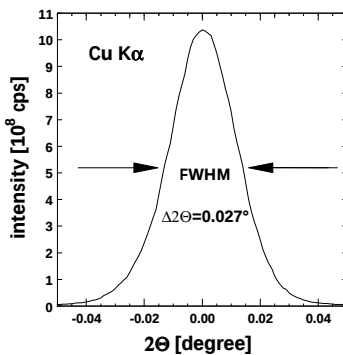


- Various parallel beam optics for single and twin mirror arrangements
- highest intensity and low divergence
 - no influence of sample surface position errors on peak position for reflectometry and diffractometry
 - superior K β suppression
 - sample fluorescence suppression
 - easy and fast sample alignment

Selected results for twin mirror arrangement:

cross intensity

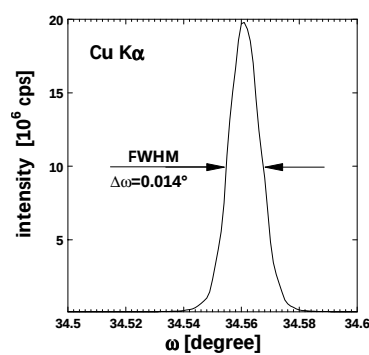
$I > 1.000.000.000$ cps



2 θ -scan without sample

angle resolution

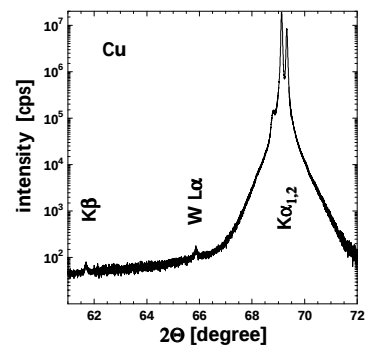
$\Delta\omega < 0.02^\circ$



rocking-scan Si(400)
silicon wafer

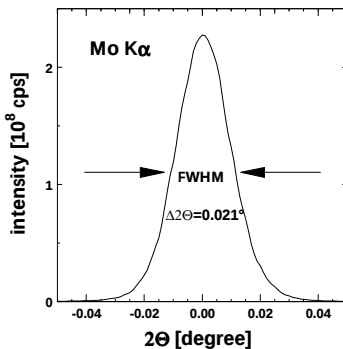
K β - suppression

$I_{\text{CuK}\alpha 1} : I_{\text{CuK}\beta} > 1.000.000 : 1$



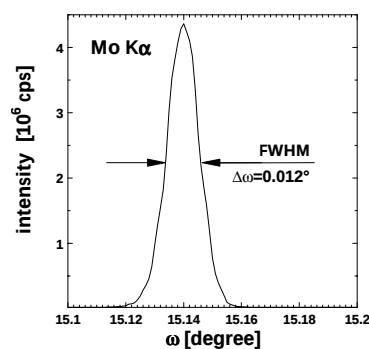
Θ -2 θ scan Si(400)
silicon wafer

$I > 200.000.000$ cps



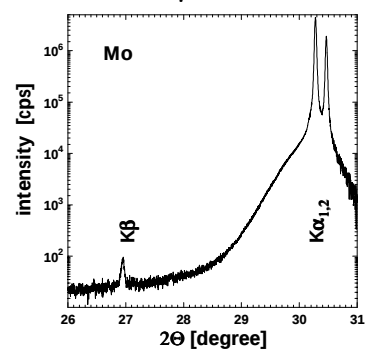
2 θ -scan without sample

$\Delta\omega < 0.02^\circ$



rocking-scan Si(400)
silicon wafer

$I_{\text{MoK}\alpha 1} : I_{\text{MoK}\beta} > 100.000 : 1$



Θ -2 θ scan Si(400)
silicon wafer

High-precision nm-Coatings for EUV and X-ray Optical Applications

St. Braun*, R. Dietsch, Th. Foltyn, Th. Holz¹, M. Moss, D. Weißbach and A. Leson

IWS Dresden, Fraunhofer Institute Material and Beam Technology, Winterbergstr. 28, D-01277 Dresden, Germany

¹ AXO Dresden GmbH, Siegfried-Rädel-Str. 31, D-01809 Heidenau, Germany

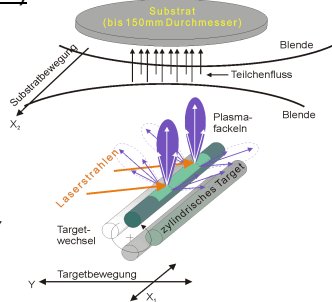
* e-mail: stefan.braun@iws.fraunhofer.de, Phone: 0351/2583432, Fax: 0351/2583300

Preparation of nm Multilayers

Pulsed Laser Deposition (PLD)

Experimental setup:

- UHV-chamber with 4 targets
- Base pressure: 10^{-8} mbar range
- Laser-target-interaction
=> Emission of a plasma plume
- Target motion in y-direction
=> Pivoting of the plasma plume, connected with a uniformization in Y direction
- Target-substrate dist.: ≈ 150 mm
- Maximum substrate size: 150 mm $\varnothing$
- Substrate motion: linear in X-direction with any v-profile

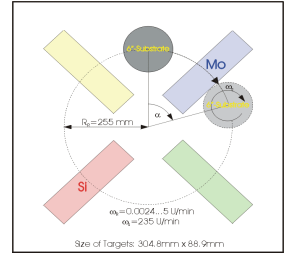


Schematic view of the target-substrate arrangement at the PLD.

Magnetron Sputter Deposition (MSD)

Experimental setup:

- UHV-chamber with 4 sources
- Base pressure: $< 2 \cdot 10^{-8}$ mbar
- Sputtering gas: Ar, stable process conditions at $p_{Ar} \geq 7 \cdot 10^{-4}$ mbar
- Target-substrate dist.: 50-100 mm
- Maximum substrate size: 150 mm $\varnothing$
- Substrate rotation: $\omega_R = 0.0024 \dots 5$ rpm
- Substrate spin: $\omega_S = 235$ rpm
- Typical deposition times: 1 period per minute

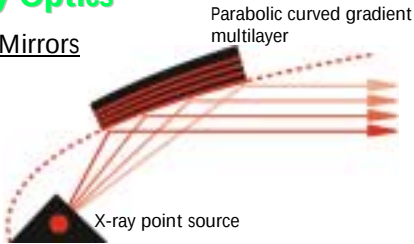


Schematic view of the target-substrate arrangement at the MSD.

Applications of nm Multilayers

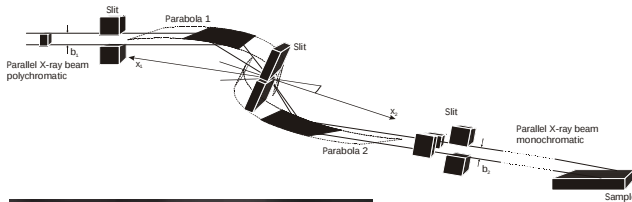
X-Ray Optics

Göbel Mirrors



- Bragg equation $n\lambda = 2d \sin \theta$ has to be fulfilled on the whole mirror surface
- Difference of set and actual d-value must be in the range of $\Delta d = \pm 0.03 \text{ nm} \dots 0.06 \text{ nm}$ on every surface point
- Particularly the deposition on pre-curved substrates is a challenge for every coating technology

Beam Collimator



2 parallel beam optics aligned on the same focal point

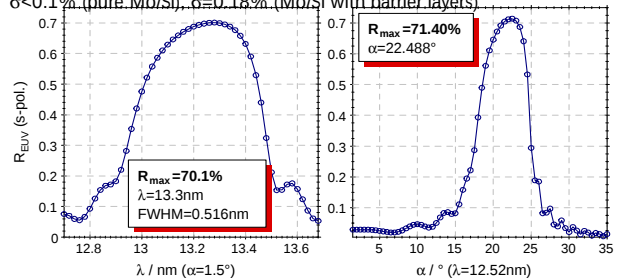
- Acceptance of parallel X-ray radiation emitted by a point focus X-ray source
- Emission of a monochromatic parallel spot

EUV Optics

Mo/Si Multilayer as EUV Reflectors

Specifications:

- Reflectance: $R = 71.4\%$ ($\lambda = 12.5 \text{ nm}$, $\alpha = 22.5^\circ$), $R = 70.1\%$ ($\lambda = 13.3 \text{ nm}$, $\alpha = 1.5^\circ$)
- Uniformity: 99.9% on substrates with 150 mm diameter ($\sigma_{\text{Multilayer period}} = 0.03 \dots 0.05\%$, $\sigma_{\text{EUV Reflectance}} = 0.05 \dots 0.08\%$)
- Run-to-run Reproducibility: $\sigma < 0.1\%$ (pure Mo/Si), $\sigma = 0.18\%$ (Mo/Si with barrier layers)

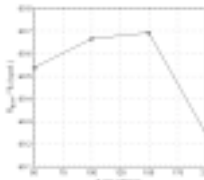


EUV reflectance of interface-optimized Mo/Si multilayers with C and B₄C barrier layers.

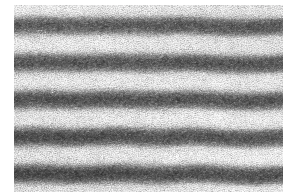
Thermal Stability

Introduction of C- and B₄C Barrier layers

=> Improvement of thermal and long-term stability



EUV reflectance depending on the annealing temperature. After thermal treatment at 200°C it remains $R_{\text{EUV}} > 69\%$



Mo/Si multilayer with B₄C barrier layers (d=0.5nm) on both interfaces after annealing at 400° for 20 min.



nanotechnologie

CC "Ultradünne funktionale Schichten"

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